# Crystal-Assisted Virtual X-Ray Spectroscopy U.Tokyo & RIKEN Y.Yamazaki

Resonant Excitation with Virtual Photons  $\cdot \cdot \cdot$  Atomic & Nuclear Systems  $\Delta E = h\nu = \gamma nh\nu/a (10^{-15}X10^8/10^{-10} n\gamma = 10^3 n\gamma eV)$ High Resolution  $\cdot \cdot \cdot \cdot 20$ ppm (->1ppm) Absolute Value High Sensitivity  $\cdot \cdot \cdot \cdot$  Highly Charged lons, Short Lived Ris, etc X-ray Dressed States

V.V.Okorokov : Yad. Fiz. 2,1009(1965) [Sov. J. Nucl. Phys. 2, 719(1966)]
S.Datz et al. : Phys. Rev. Lett. 40, 843(1978)
T.Azuma et. al. : Phys. Rev. Lett. 83, 528(1999)

#### Resonant Coherent Excitation under Planar Channeling Condition



$$E = \frac{\gamma h n}{a} \left( \frac{k \cos \theta}{A} + \frac{l \sin \theta}{B} \right)$$

 $\gamma = (1 - (\upsilon/c)^2)^{-1/2}$ 

 $\upsilon$ : ion velocity

- $\theta$ : angle between ion velocity & crystal string in the plane
- a : lattice constant

k,l: integer

## HIMAC Accelerator Configulation



#### Experimental Setup for Virtual Photon Spectroscopy



#### 390MeV/u Ar + Si(220)







Emission Angle Differential Excitation





S.Datz e al., Phys.Rev.Lett.40,843(1978)



# **Corrections : Crystal Potential**

 $\Delta \varepsilon = <1s|U|1s> - <n|U|n> ~k(n^2/q)^2/2 ~(~0.4eV \text{ for Ar1s-2p in Si})$ 

## Rabi Oscillation :

 $\tau = 2M^2 \sin(\Omega t)/\Omega$  (~6µm for 390MeV/u Ar in Si) where  $\Omega = (\Delta^2 + 4M^2)^{1/2}$ ,  $\Delta = (\epsilon_2 - \epsilon_1) - 2\pi n\gamma \nu/a$ 

(Virtual-) Photon Flux  $\sim 10^{24}$  photons/mm<sup>2</sup>/sec/eV

### Spectroscopy of He-like Fe<sup>24+</sup> ion



# Limiting Factors of the Resolution

#### Coherent Length: $l_{ion} \sim (q^4 \rho_{el} \sigma_{ion}(\upsilon/q)/n^4)^{-1}$ (~15µm for 390MeV/u Ar(2p) in Si[110])

- $l_{\text{dexc}} \sim 25(\gamma \upsilon/a^3 q^4)$  (~4.6µm for 390MeV/u Ar(2p) in Si[110])
- $l_{osc} \sim \upsilon/\omega_{osc}$  (~2µm for 390MeV/u Ar in Si[110])  $\omega_{osc} \sim (kq/m\gamma)^{1/2}$  (U=kx<sup>2</sup>/2: k~0.033a.u. for Si[110])

 $\Delta \epsilon / \epsilon \sim a / l_{min}$  (~10<sup>-5</sup> for 390MeV/u Ar in Si[110])

Energy Loss:  $\Delta v_{E-loss}/v$ 

 $(\sim 3 \times 10^{-6} / \mu m \text{ for } 390 \text{MeV/u Ar in Si[110]})$ 

Thermal Expansion

κ (~ 2.5x10<sup>-6</sup>/K)

#### Case Study: Possible Accuracy of 1s Lamb Shift

$$\begin{split} R &\sim _{Lamb} ~~_{1s\text{-}2p} \sim 10^{\text{-}6}Z^4 ~~_{R}/Z^2 ~~_{R} \sim 10^{\text{-}6}Z^2 \\ \text{If} ~~_{1s\text{-}2p} \text{ is determined with the precision of ppm, relative accuracy of 1s Lamb shift could be} \\ R_{Lamb} &\sim ~~_{Lamb} ~~_{Lamb} \sim Z^{\text{-}2} \end{split}$$



P.J.Mohr, G.Plunien, and G.Soff, Phys.Rep.293,227(1998)

#### Excitation Dynamics : X-rays & Convoy Electrons



390MeV/u Ar<sup>17+</sup> Resonance Profile for Charge State, Convoy, & X-ray Yields



X-ray Emission from Fe<sup>25+</sup> & Fe<sup>24+</sup>





Distance from channel center (A)

### Resonance Energy of 1s-2p in Si[110]



X-ray energies from rce process for relativistic ions



angular distribution :  $\theta \sim 1/\gamma$ 

$$\varepsilon = \gamma (1 + \beta \cos \theta) \Delta E \qquad \succ (2\gamma - \gamma \theta^2/2) \Delta E$$

$$\gamma \rightarrow \infty$$

$$\theta \rightarrow 0$$

@20GeV/u U  $\epsilon \sim 3MeV$ 



# Summary

New Way of High Resolution Spectroscopy in X-ray Range

1-10 Million lons are Enough • • • HCl, Short-Lived Nuclei

Dynamics in Ion-Crystal Interaction

X-ray Dressed States

New Polarized Gamma Ray Source · · Conversion from Virtual Photon to Real Photon



# Angular Distribution of X-rays

$$I(\theta') = A \cos \theta'$$
  
$$\tan \theta = \frac{(1 - \beta^2)^{1/2} \sin \theta'}{\cos \theta' + \beta}$$